# 1500 Watt Peak Power Zener Transient Voltage Suppressors

#### **Unidirectional\***

The SMC series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SMC series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable Surmetic™ package and is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

#### **Specification Features:**

- Working Peak Reverse Voltage Range 5.8 to 77.8 V
- Standard Zener Breakdown Voltage Range 6.8 to 91 V
- Peak Power 1500 Watts @ 1 ms
- ESD Rating of Class 3 (>16 KV) per Human Body Model
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage < 5 μA Above 10 V
- UL 497B for Isolated Loop Circuit Protection
- Maximum Temperature Coefficient Specified
- Response Time is Typically < 1 ns

#### **Mechanical Characteristics:**

**CASE:** Void-free, transfer-molded, thermosetting plastic

**FINISH:** All external surfaces are corrosion resistant and leads are readily solderable

### ${\bf MAXIMUM\ CASE\ TEMPERATURE\ FOR\ SOLDERING\ PURPOSES:}$

260°C for 10 Seconds

**LEADS:** Modified L—Bend providing more contact area to bond pads

**POLARITY:** Cathode indicated by molded polarity notch

**MOUNTING POSITION:** Any

#### **MAXIMUM RATINGS**

Please See the Table on the Following Page



#### ON Semiconductor™

http://onsemi.com

PLASTIC SURFACE MOUNT ZENER OVERVOLTAGE TRANSIENT SUPPRESSORS 5.8–78 VOLTS 1500 WATT PEAK POWER





SMC CASE 403 PLASTIC

#### MARKING DIAGRAM



Y = Year

WW = Work Week

xxxA = Specific Device Code (See Table on Page 3)

#### ORDERING INFORMATION

Device †	Package	Shipping			
1.5SMCxxxAT3	SMC	2500/Tape & Reel			

Devices listed in **bold**, **italic** are ON Semiconductor **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

†The "T3" suffix refers to a 13 inch reel.



<sup>\*</sup>Bidirectional devices will not be available in this series.

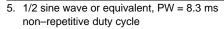
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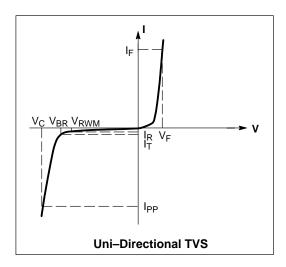
Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1.) @ T <sub>L</sub> = 25°C, Pulse Width = 1 ms	P <sub>PK</sub>	1500	W
DC Power Dissipation @ T <sub>L</sub> = 75°C  Measured Zero Lead Length (Note 2.)  Derate Above 75°C  Thermal Resistance from Junction to Lead	P <sub>D</sub>	4.0 54.6 18.3	W mW/°C °C/W
DC Power Dissipation (Note 3.) @ T <sub>A</sub> = 25°C Derate Above 25°C Thermal Resistance from Junction to Ambient	P <sub>D</sub>	0.75 6.1 165	W mW/°C °C/W
Forward Surge Current (Note 4.) @ T <sub>A</sub> = 25°C	I <sub>FSM</sub>	200	А
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

- 1. 10 X 1000 μs, non-repetitive
- 2. 1" square copper pad, FR-4 board
- 3. FR-4 board, using ON Semiconductor minimum recommended footprint, as shown in 403 case outline dimensions spec.
- 4. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}\text{C}$ unless otherwise noted, $V_F = 3.5 \text{ V Max}$ . @ $I_F$ (Note ) = 100 A)

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	Clamping Voltage @ I <sub>PP</sub>					
V <sub>RWM</sub>	Working Peak Reverse Voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>					
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>					
I <sub>T</sub>	Test Current					
$\Theta V_{BR}$	Maximum Temperature Coefficient of $V_{BR}$					
I <sub>F</sub>	Forward Current					
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>					





#### ELECTRICAL CHARACTERISTICS: Devices listed in bold, italic are ON Semiconductor Preferred devices.)

		V <sub>RWM</sub>		Breakdown Voltage		V <sub>C</sub> @ I <sub>PP</sub> (Note 8.)				
	Device	(Note 6.)	I <sub>R</sub> @ V <sub>RWM</sub>	V <sub>BR</sub> Volts (Note 7.)		@ ե	V <sub>C</sub>	I <sub>PP</sub>	$\Theta V_{BR}$	
Device	Marking	Volts	μ <b>Α</b>	Min	Nom	Max	mA	Volts	Amps	%/°C
1.5SMC6.8AT3	6V8A	5.8	1000	6.45	6.8	7.14	10	10.5	143	0.057
1.5SMC7.5AT3	7V5A	6.4	500	7.13	7.5	7.88	10	11.3	132	0.061
1.5SMC8.2AT3	8V2A	7.02	200	7.79	8.2	8.61	10	12.1	124	0.065
1.5SMC9.1AT3	9V1A	7.78	50	8.65	9.1	9.55	1	13.4	112	0.068
1.5SMC10AT3 1.5SMC11AT3 1.5SMC12AT3 1.5SMC13AT3	10A 11A 12A 13A	8.55 9.4 10.2 11.1	10 5 5 5	9.5 10.5 11.4 12.4	10 11 12 13	10.5 11.6 12.6 13.7	1 1 1	14.5 15.6 16.7 18.2	103 96 90 82	0.073 0.075 0.078 0.081
1.5SMC15AT3	<b>15A</b>	<b>12.8</b>	<b>5</b>	<b>14.3</b>	15	<b>15.8</b>	1	<b>21.2</b>	<b>71</b>	<b>0.084</b>
1.5SMC16AT3	16A	13.6	5	15.2	16	16.8	1	22.5	67	0.086
1.5SMC18AT3	18A	15.3	5	17.1	18	18.9	1	25.2	59.5	0.088
1.5SMC20AT3	20A	17.1	5	19	20	21	1	27.7	54	0.09
1.5SMC22AT3	22A	18.8	5	20.9	22	23.1	1	30.6	49	0.092
1.5SMC24AT3	<b>24A</b>	<b>20.5</b>	<b>5</b>	<b>22.8</b>	<b>24</b>	<b>25.2</b>	1	<b>33.2</b>	<b>45</b>	<b>0.094</b>
1.5SMC27AT3	27A	23.1	5	25.7	27	28.4	1	37.5	40	0.096
1.5SMC30AT3	30A	25.6	5	28.5	30	31.5	1	41.4	36	0.097
1.5SMC33AT3	33A	28.2	5	31.4	33	34.7	1	45.7	33	0.098
1.5SMC36AT3	36A	30.8	5	34.2	36	37.8	1	49.9	30	0.099
1.5SMC39AT3	39A	33.3	5	37.1	39	41	1	53.9	28	0.1
1.5SMC43AT3	43A	36.8	5	40.9	43	45.2	1	59.3	25.3	0.101
1.5SMC47AT3	<b>47A</b>	<b>40.2</b>	<b>5</b>	<b>44.7</b>	<b>47</b>	<b>49.4</b> 53.6 58.8 65.1	1	<b>64.8</b>	<b>23.2</b>	<b>0.101</b>
1.5SMC51AT3	51A	43.6	5	48.5	51		1	70.1	21.4	0.102
1.5SMC56AT3	56A	47.8	5	53.2	56		1	77	19.5	0.103
1.5SMC62AT3	62A	53	5	58.9	62		1	85	17.7	0.104
1.5SMC68AT3 1.5SMC75AT3 1.5SMC82AT3 1.5SMC91AT3	68A <b>75A</b> 82A 91A	58.1 <b>64.1</b> 70.1 77.8	5 <b>5</b> 5 5	64.6 <b>71.3</b> 77.9 86.5	68 <b>75</b> 82 91	71.4 <b>78.8</b> 86.1 95.5	1 1 1	92 <b>103</b> 113 125	16.3 <b>14.6</b> 13.3 12	0.104 <b>0.105</b> 0.105 0.106

<sup>6.</sup> A transient suppressor is normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal to or greater than the DC or continuous peak operating voltage level.

<sup>7.</sup>  $V_{BR}$  measured at pulse test current  $I_T$  at an ambient temperature of 25°C.

<sup>8.</sup> Surge current waveform per Figure 2 and derate per Figure 3 of the General Data – 1500 Watt at the beginning of this group.

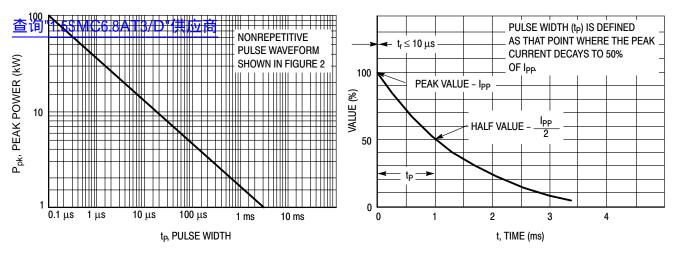


Figure 1. Pulse Rating Curve

Figure 2. Pulse Waveform

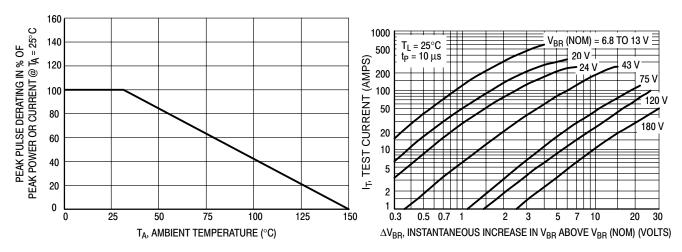


Figure 3. Pulse Derating Curve

Figure 4. Dynamic Impedance

#### **UL RECOGNITION**

The entire series has *Underwriters Laboratory Recognition* for the classification of protectors (QVGV2) under the UL standard for safety 497B and File #116110. Many competitors only have one or two devices recognized or have recognition in a non-protective category. Some competitors have no recognition at all. With the UL497B recognition, our parts successfully passed several tests

including Strike Voltage Breakdown test, Endurance Conditioning, Temperature test, Dielectric Voltage-Withstand test, Discharge test and several more.

Whereas, some competitors have only passed a flammability test for the package material, we have been recognized for much more to be included in their Protector category.

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#### RESPONSE TIME

In most applications, the transient suppressor device is placed in parallel with the equipment or component to be protected. In this situation, there is a time delay associated with the capacitance of the device and an overshoot condition associated with the inductance of the device and the inductance of the connection method. The capacitive effect is of minor importance in the parallel protection scheme because it only produces a time delay in the transition from the operating voltage to the clamp voltage as shown in Figure 5.

The inductive effects in the device are due to actual turn-on time (time required for the device to go from zero current to full current) and lead inductance. This inductive effect produces an overshoot in the voltage across the equipment or component being protected as shown in Figure 6. Minimizing this overshoot is very important in the application, since the main purpose for adding a transient suppressor is to clamp voltage spikes. The SMC series have a very good response time, typically < 1 ns and negligible inductance. However, external inductive effects could produce unacceptable overshoot. Proper circuit layout,

#### **APPLICATION NOTES**

minimum lead lengths and placing the suppressor device as close as possible to the equipment or components to be protected will minimize this overshoot.

Some input impedance represented by  $Z_{in}$  is essential to prevent overstress of the protection device. This impedance should be as high as possible, without restricting the circuit operation.

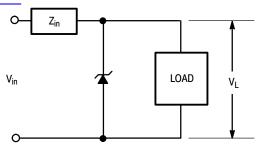
#### **DUTY CYCLE DERATING**

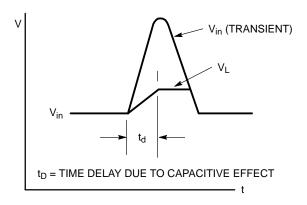
The data of Figure 1 applies for non-repetitive conditions and at a lead temperature of 25°C. If the duty cycle increases, the peak power must be reduced as indicated by the curves of Figure 7. Average power must be derated as the lead or ambient temperature rises above 25°C. The average power derating curve normally given on data sheets may be normalized and used for this purpose.

At first glance the derating curves of Figure 7 appear to be in error as the 10 ms pulse has a higher derating factor than the 10  $\mu$ s pulse. However, when the derating factor for a given pulse of Figure 7 is multiplied by the peak power value of Figure 1 for the same pulse, the results follow the expected trend.

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#### **TYPICAL PROTECTION CIRCUIT**





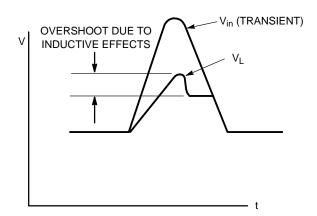


Figure 5.

Figure 6.

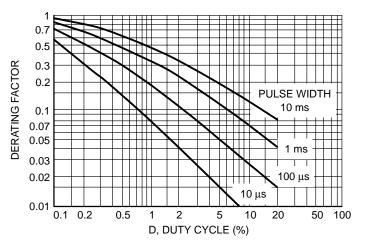


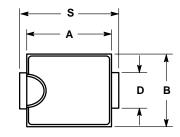
Figure 7. Typical Derating Factor for Duty Cycle

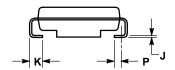
#### **OUTLINE DIMENSIONS**

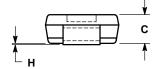
## **Transient Voltage Suppressors – Surface Mounted**

### 1500 Watt Peak Power



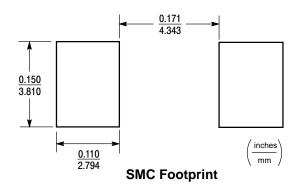






- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION.
- DIMENSION P.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.260	0.280	6.60	7.11	
В	0.220	0.240	5.59	6.10	
С	0.075	0.095	1.90	2.41	
D	0.115	0.121	2.92	3.07	
Н	0.0020	0.0060	0.051	0.152	
J	0.006	0.012	0.15	0.30	
K	0.030	0.050	0.76	1.27	
Р	0.020 REF		0.51 REF		
S	0.305	0.320	7.75	8.13	



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